

Mod 1, 2, 3 → Q1, Q2    Mod 4, 5, 6, 7 → Q3, Q4

$$R = \frac{V}{I}$$

$$N = R \cdot I$$

$$I = \frac{V}{R}$$

## Components Wireless Tech.

### Mod 1 Transmission Lines

- Lumped components:  $R, L, C, G$

$$R [Ω] \quad L [H] \quad G [S] \quad C [F]$$

$$\frac{dV}{dz} = -(R + j\omega L) I \quad \frac{dI}{dz} = - (G + j\omega C) V$$

- Propagation const:  $\gamma = \alpha + j\beta = \sqrt{(R+j\omega L)(G+j\omega C)}$

- $V(z) = V_0^+ e^{-\gamma z} + V_0^- e^{+\gamma z}$

- $I(z) = I_0^+ e^{-\gamma z} + I_0^- e^{+\gamma z}$

- Characteristic Impedance:  $\sqrt{\frac{R+j\omega L}{G+j\omega C}}$  → lossless:  $\sqrt{G/C}$

- lossless line:  $R=0=G$ .  $G=1/R$ . → conductance.

- $\Rightarrow \gamma = jB \quad B = \sqrt{G/C} = \omega \sqrt{L/C}$

- Phase velocity:  $v_p = \omega/B = \sqrt{C/L}$ ;  $\lambda = \frac{2\pi}{B} = \frac{2\pi}{\omega \sqrt{L/C}}$

- $\Gamma = \frac{Z_L - Z_0}{Z_L + Z_0} = \frac{V_0^-}{V_0^+}$

$$\Gamma = \frac{2\pi}{\lambda}$$

- input impedance:  $Z_{in} = Z_0 \frac{Z_L + jZ_0 \tan(\beta l)}{Z_0 + jZ_L \tan(\beta l)}$

- Quarter wave transformer  $\rightarrow \frac{Z_{in}}{Z_L} = \frac{1}{\Gamma}$ .  $l = \frac{\lambda}{4}$ .

- $\rightarrow \Gamma \cdot \beta l = \frac{2\pi}{\lambda} \cdot \frac{\lambda}{4} = \frac{\pi}{2} \rightarrow \tan(\pi/2) = \infty$

- $Z_{in} = Z_0 \cdot \frac{Z_0}{Z_L} = Z_0^2/Z_L$

- Perfect match  $\frac{Z_{in}}{Z_L} = 1 \Rightarrow Z_{in} = Z_L$

- or  $Z_2 = Z_1 Z_3$

- Series:  $Z_R = R$ ;  $Z_L = j\omega L$ ;  $Z_C = \frac{1}{j\omega C}$

- Shunt:  $\gamma_R = 1/R$ ;  $\gamma_L = j\omega L$ ;  $\gamma_C = j\omega C$

## Power

- Power of reflection:  $|T|^2$

→ Power loss due to reflection,  $1 - |T|^2$

- $dBm = 10 \log_{10} \left( \frac{P_{out}}{1mW} \right)$

- $dB = 10 \log_{10} \left( \frac{P_{in}}{P_{out}} \right)$

$$10 \frac{dP}{10} = mW = W$$

## Module 2 - Passive Microwave Networks

$$A \text{ matrix: } \begin{bmatrix} V_1 \\ V_2 \end{bmatrix} = A \begin{bmatrix} I_1 \\ I_2 \end{bmatrix} \quad \begin{bmatrix} V_1 \\ I_1 \end{bmatrix} = A \begin{bmatrix} V_2 \\ I_2 \end{bmatrix}$$

$$T \text{ matrix: } \begin{bmatrix} V_1^+ \\ V_1^- \end{bmatrix} = T \begin{bmatrix} V_2^+ \\ V_2^- \end{bmatrix}$$

$$S \text{ matrix: } \begin{bmatrix} V_1^- \\ V_2^+ \end{bmatrix} = S \begin{bmatrix} V_1^+ \\ V_2^- \end{bmatrix}$$

$$A = D_1 T C_2 \rightarrow D_1 F T = C_1 T D_2$$

$$D \text{ matrix: decompose: } 1/2 \begin{bmatrix} 1 & 3 \\ 1 & -2 \end{bmatrix} \begin{bmatrix} V_1 \\ I_1 \end{bmatrix} = \begin{bmatrix} V_1^+ \\ V_1^- \end{bmatrix}$$

$$C \text{ matrix: compose: } \begin{bmatrix} 1 & 1 \\ Y & -Y \end{bmatrix} \begin{bmatrix} V_1^+ \\ V_1^- \end{bmatrix} = \begin{bmatrix} V_1 \\ I_1 \end{bmatrix}$$

## Module 3 - Antenna Parameters and Theory

- Field Regions of antenna behaviour.

• reactive near field?

$R \rightarrow$  distance from antenna.

$$\text{FSPL} = \left( \frac{4\pi d}{\lambda} \right)^2$$

$D \rightarrow$  dimension of antenna.

$$R_1 \rightarrow 0.62 \sqrt{\frac{D^3}{\lambda}} \quad R_2 = \frac{\pi D^2}{\lambda}$$

• reactive near field:  $R < R_1$

• radiating near field:  $R_1 < R < R_2$ .

• far field :  $R \geq R_2$ .  $R \gg D, \lambda \rightarrow$  behave like plane waves

• radius of circle:  $r = D/2 \rightarrow \text{Area} = \pi r^2 \rightarrow \pi (D/2)^2 = (\pi D^2)/4 \rightarrow A_e \text{ could be}$

• gain aperture relation:  $A_e/G = \lambda^2 / 4\pi \rightarrow G = A_e \left( \frac{4\pi}{\lambda^2} \right)$

• short dipole  $A_e$ :  $A_{e,\text{max}} = \pi l^2 / 8\pi$

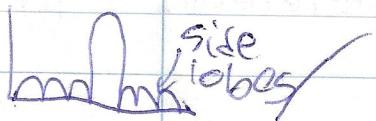
• Friis transmission:  $P_{Rx} = P_{Tx} = G_{Tx} \times \text{ER} \times P_{Tx} \times G_{Rx} \times \log \left( \frac{4\pi d}{\lambda^2} \right)^2$

radiation pattern 3D



distance  
between  
antennas

radiation pattern 2D



### Module 3 - Continue.

- $\text{Wav}(\vec{r}) = \frac{1}{2} \text{Re}(\vec{E}(\vec{r}) \times \vec{H}^*(\vec{r}))$ . : time avg power density.
- radiation intensity (distance independent):  $U(0, \varphi) = R^2 \text{Wav}(\vec{r})$

- directivity:  $D_g = \frac{U(0, \varphi)}{U_0}$   $U_0 = \frac{\text{Prod}}{\eta \gamma}$
- gain:  $G_g = \frac{4\pi D_g (\text{Prod})}{P_{in}}$   $\frac{4\pi}{R^2} U(0, \varphi)$
- gain to directivity:  $G_g = \eta \epsilon \epsilon_c D_g$

$\epsilon_c = \epsilon_{rad} \rightarrow \epsilon_r = 1 - |\Gamma|^2 \rightarrow$  reflection loss  
 $\hookrightarrow \epsilon_{cd} \rightarrow$  conduction / dielectric loss

$\epsilon \rightarrow \text{radiation efficiency (Prod)}$

$\epsilon_c = \frac{\text{Prod}}{P_{in}} = \frac{R_{rad}}{R_{rad} + R_{loss}}$

Polarization → orientation / trajectory

$$E_\theta = \bar{E}_\theta \cos(\omega t - KR + \varphi_\theta)$$

$$E_\phi = \bar{E}_\phi \cos(\omega t - KR + \varphi_\phi)$$

- Axial ration:  $AR = \frac{\max(E_\theta \bar{E}_\theta + E_\phi \bar{E}_\phi)}{\min(E_\theta \bar{E}_\theta + E_\phi \bar{E}_\phi)}$

$\nearrow \text{linear: } \infty$

$\nearrow \text{circular: } 1$

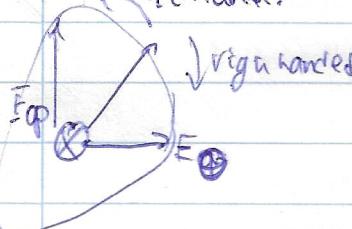
$\searrow \text{elliptical: } AR \cos \varphi$

- linear:  $\Delta\varphi = \varphi_\theta - \varphi_\phi = n\pi \in \mathbb{N}_0$ .

- circular:  $\bar{E}_\theta = \bar{E}_\phi$ ;  $\Delta\varphi = \varphi_\theta - \varphi_\phi = \pm (1/2 + 2n)\pi, n \in \mathbb{N}_0$ .

- elliptical:  $\bar{E}_\theta \neq \bar{E}_\phi$ ;  $\Delta\varphi = \varphi_\theta - \varphi_\phi = \pm (1/2 + 2n)\pi, n \in \mathbb{N}_0$

left handed.



$$\Delta\varphi = \varphi_\theta - \varphi_\phi \neq \pm n/2\pi, n \in \mathbb{N}_0 \rightarrow \text{elliptical}$$

rotation direction.

abs bandwidth:  $BW = f_{\text{max}} - f_{\text{min}}$ .

% narrowband bandwidth:  $\rho = BW/f_c$ .

efficiency  $\epsilon_g \text{ eff} = 20\%$

$$G_g = D_g \cdot \epsilon \epsilon_c$$

$$G_g = 10 \log_{10}(D_g) + 10 \log_{10}(0.2)$$

## Effective Aperature

Received power:  $P_f = W_{inc} A_e$ .

effective aperture general form:  $A_e = \frac{P_f}{W_{inc}} = \frac{V_f^2}{2W_{inc}((R_f + R_{rad} + R_{loss})^2 + (X_f + x_{rad})^2)}$

Matched case:

max aperture:  $A_e = \frac{V_f^2}{8W_{inc}(R_{rad} + R_{loss})}$

short dipole:  $A_e = \frac{\lambda^2}{8\pi} \quad \text{eg: area} = \pi r^2 = A_e \rightarrow r = \lambda/2$

(plane wave in free space) power density:  $W_{inc} = E^2 / 2\eta \quad \eta = 120\pi \quad \text{free space.}$

\* Aperture-gain link =  $A_e/G = \lambda^2 / 4\pi \quad \text{radiation efficiency}$   
 $\eta = \frac{P_{rad}}{P_{in}} = \frac{R_{rad}}{R_{in} + R_{loss}}$

## Propagation Channel

FSPL:  $(\frac{4\pi d}{\lambda})^2$

Dated = D

$\propto P_{Rx} = P_{Tx} G_{Tx} G_{Rx} \left(\frac{1}{4\pi d}\right)^2$

\* Isootropic Power density at distance:  $W_{inc, iso} = \frac{P_{rad}}{4\pi R^2}$

## Polarization Determination

Linear:  $1e^{j\omega t}\bar{x} + 0e^{j\omega t}\bar{y}$

$$0e^{j\omega t}\bar{x} + 2e^{j\omega t}\bar{y}$$

$$1e^{j\omega t}\bar{x} + 1e^{j\omega t}\bar{y}$$

$$2e^{j\omega t}\bar{x} + 2e^{j(\omega+\pi)}\bar{y}$$

number

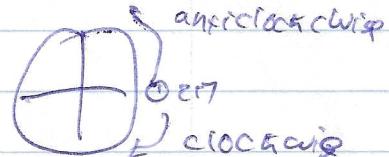
$$\rightarrow 2\pi, 3\pi \text{ etc.} \rightarrow \oplus \ominus \oplus = \pi \pi$$

Circular: (-) - <sup>clockwise</sup> (+) - <sup>anticlockwise</sup>  $\pi/2 = \oplus \ominus$

$$E_\oplus = E_\ominus$$

$$1e^{j\omega t}\bar{x} + 1e^{j(\omega+\pi/2)}\bar{y}$$

$$2e^{j\omega t}\bar{x} + 2e^{j(\omega-\pi/2)}\bar{y}$$



Elliptical: (-) - clockwise (+) - anticlockwise

$$E_\oplus \neq E_\ominus ; \quad \pi/2 = \Theta - \phi \text{ or if } \frac{\pi}{2} \rightarrow \text{tilted ellipse}$$

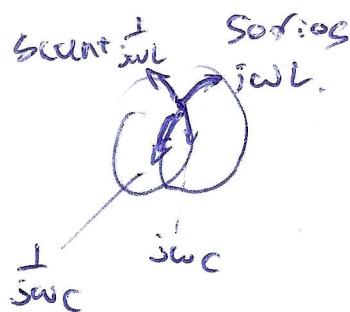
$$1e^{j\omega t}\bar{x} + 2e^{j(\omega+\pi/2)}\bar{y} \quad \text{normal.}$$

$$1e^{j\omega t}\bar{x} + 2e^{j(\omega+\pi+\pi/2)}\bar{y} \quad \text{tilted.}$$

$g_s \cdot 84 \cdot 10^{13}$

4 GHz

1.



$$\text{load} - 0.9j = 2$$

$$50 \rightarrow -45j = 2$$

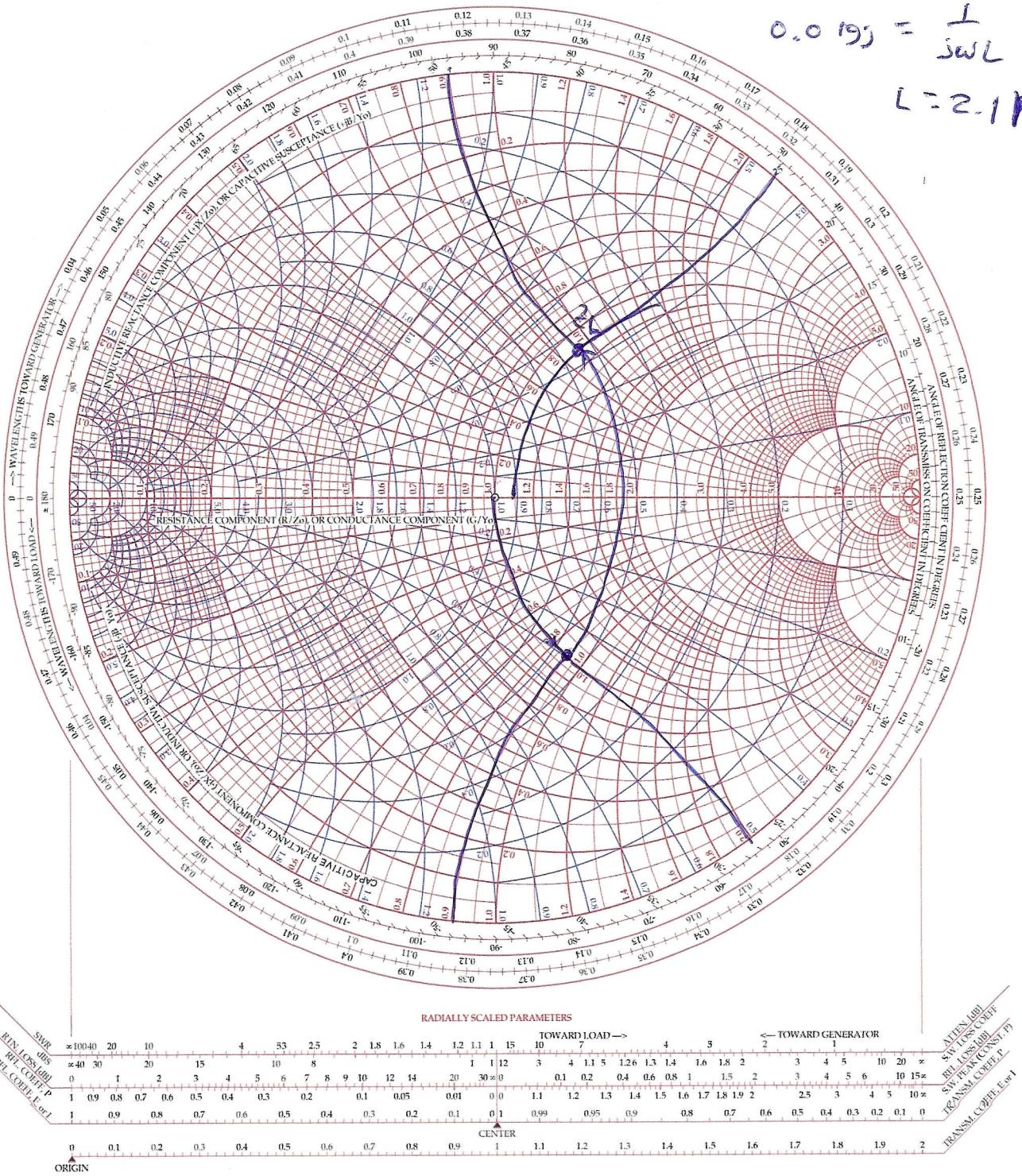
$$jwC \frac{1}{-45j} \rightarrow C = 0.88 \text{ pF}$$

$$2. \text{ more}: (0.5 - 0.45j) = 0.95j$$

$$0.95j \cdot \frac{1}{50} = 0.019j$$

$$0.019j = \frac{1}{jwL}$$

$$L = 2.1 \text{ nH}$$



RF systems: signal conditioning to minimize:

- noise
- nonlinearity
- energy loss

(mic) input  $\rightarrow$  filter etc.  $\rightarrow$  load splitting

High frequency  
RF needs  
account for  
parasitics

RF blocks: Transceiver: LNA, PA, mixers, Filters

List of Equations (only some of these equations are required to solve question 3 and 4)

$$\Gamma = \frac{Z_L - Z_0}{Z_L + Z_0}$$

Power definitions

2-port network

Gains

Constant gain circles

|   |  |  |
|---|--|--|
| Power delivered to the load   | $P_L = \frac{ V_2 ^2}{2Z_0} (1 -  \Gamma_L ^2)$  | Power gain<br>$G = \frac{P_L}{P_{in}} \rightarrow$ Power gain  |
| Input power to the network  | $P_{in} = \frac{ V_1^+ ^2}{2Z_0} (1 -  \Gamma_{in} ^2)$  |  |
| Input and output reflection coefficients of a transistor with a source and load: general case                                 | $\Gamma_{in} = \frac{V_1^-}{V_1^+} = S_{11} + \frac{S_{12}S_{21}\Gamma_L}{1 - S_{22}\Gamma_L}$<br>$\Gamma_{out} = \frac{V_2^-}{V_2^+} = S_{22} + \frac{S_{12}S_{21}\Gamma_S}{1 - S_{11}\Gamma_S}$            |  |
| Input and output reflection coefficients of a transistor with a source and load: unilateral case<br><br>Max CTU, max achieved | $\Gamma_{in} = \frac{V_1^-}{V_1^+} = S_{11}$<br>$\Gamma_{out} = \frac{V_2^-}{V_2^+} = S_{22}$  | $S_{12} = 0$ meaning only dependent on original signal setting no interaction with port 2 $\rightarrow$ 1 traveling waves  |
| Gain of the input matching network  | $G_S = \frac{1 -  \Gamma_S ^2}{ 1 - \Gamma_{in}\Gamma_S ^2}$   |  |
| Gain of the output matching network   | $G_L = \frac{1 -  \Gamma_L ^2}{ 1 - S_{22}\Gamma_L ^2}$  |  |
| Gain of the transistor (unilateral case)  | $G_0 =  S_{21} ^2$   |  |
| Transducer gain of the basic amplifier circuit (input matching, unilateral transistor, output matching)                       | $G_T = G_S G_0 G_L$<br>$G_{T,dB} = G_{S,dB} + G_{0,dB} + G_{L,dB}$   | also unilateral.   |
| Maximum gain of the input and output matching networks  | $G_{S_{max}} = \frac{1}{1 -  S_{11} ^2}$ ,<br>$G_{L_{max}} = \frac{1}{1 -  S_{22} ^2}$   | $S_{12} = 0$   |
| Maximum transducer power gain, unilateral case  | $G_{TU_{max}} = \frac{1}{1 -  S_{11} ^2}  S_{21} ^2 \frac{1}{1 -  S_{22} ^2}$  | $G_{TU_{max}} = G_{S_{max}} G_0 G_{L_{max}}$   |
| Normalized gain factors $g_S$ and $g_L$   | $g_S = \frac{G_S}{G_{S_{max}}} = \frac{1 -  \Gamma_S ^2}{ 1 - S_{11}\Gamma_S ^2} (1 -  S_{11} ^2)$ ,<br>$g_L = \frac{G_L}{G_{L_{max}}} = \frac{1 -  \Gamma_L ^2}{ 1 - S_{22}\Gamma_L ^2} (1 -  S_{22} ^2)$ . |  |
| Center and radius of the constant gain circle for the input matching network  | $C_S = \frac{g_S S_{11}^*}{1 - (1 - g_S) S_{11} ^2}$ ,<br>$R_S = \frac{\sqrt{1 - g_S} (1 -  S_{11} ^2)}{1 - (1 - g_S) S_{11} ^2}$  | <ul style="list-style-type: none"> <li>• Depict specific impedance matching conditions for specific power gain value.</li> <li>• points on circle load, source impedance to produce specified gain.</li> </ul> |
| Center and radius of the constant gain circle for the output matching network   | $C_L = \frac{g_L S_{22}^*}{1 - (1 - g_L) S_{22} ^2}$ ,<br>$R_L = \frac{\sqrt{1 - g_L} (1 -  S_{22} ^2)}{1 - (1 - g_L) S_{22} ^2}$  |  |

There are 2 types of Smith Chart circles:

- 1) Stability circles
- 2) Constant Gain Circles

## Mod 5 Noise and LNA Design

• Thermal Noise Power:  $P_n = k_B T_B \rightarrow \text{BW}$   
Boltzmann const

• White noise:  $P_n = \frac{V_n^2}{4 R_N} = k_B T_B$

• Noise Temp:  $T_e = N_0 / k_B B$

### Noise sources

- thermal; shot; flicker ( $1/f$ )
- burst (random telegraph)
- avalanche (carrier multip.)

### LNA focus

- high gain
- Input/Output matching
- low noise figure
- stability across operating bands

### Design for specific noise figure

- $F_{\text{op}}, V_n, f_{\text{min}}$  known transistors
- amplifier specification requires noise figure:  $F$  and gain  $G$ .
1. calc  $N$  (noise figure)
2. calc  $C_f, R_f$
3. draw circles for the required  $F$  and input section constant gain circle for several  $G$ s.
4. CHOOSE  $f_s$  such on desired noise circle and gain circle.
5. remaining gain come from transistor/Output matching/ $\lambda$  stage.

## Mod 6 Basics of Power Amplifiers and Mixers - Theory and Formulas

### Small Signal Params:

1. gain

2. noise fig [NF]

3. Input Third-Order Intercept Point IIP3.

4. Input 2nd-order Intercept Point IIP2.

### Large Signal Params

i. & I<sub>dB</sub> - compression point (P<sub>dB</sub>)

### available noise power

$$P_n = \frac{V_n^2}{4 R_N} = k_B T_B$$

### non linearizing device output:

$$v_{out}(t) = a_1 v_{in}(t) + a_2 v_{in}^2(t) + a_3 v_{in}^3(t) + \dots$$

### cascade IIP3:

$$\frac{1}{IIP3_{\text{total}}} = \frac{1}{IIP3_1^2} + \frac{1}{G_1^2 IIP3_2^2} + \dots$$

### Mixer

RX-case - down conversion

Mixer tone - domain output:

$$x_{IT}(t) = A_{RF} \cos(\omega_{RF} t + \omega_{LO}) + \cos(\omega_{RF} - \omega_{LO})$$

Intermediate freq:

$$\Delta f_{C/I/F} = \omega_{RF} - \omega_{LO}$$

freq domain:  $X_{out}(\omega) = X_{in}(\omega) * X_{LO}(\omega)$

TX case - upconversion

$$\omega_{RF} = \omega_{IF} + \omega_{LO}$$

### Power Amplifier

$$P_{load} > \frac{V_{load}^2}{R_L}$$

$$N_{max} = \frac{D}{4} \approx 78.5\%$$

$$R_L = \frac{2V_{DD} - V_{min}}{I_{max}}$$

### PA Performance Params

• P<sub>dB</sub>: Output 1dB compression point.

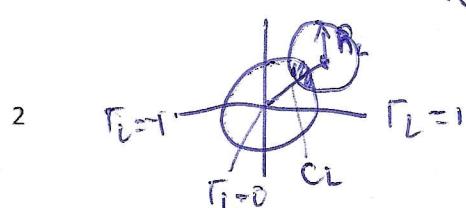
• P<sub>max</sub>: max output power achievable.

• Efficiency: ratio of RF Output power to DC input power

• unilateral amplifier: no feedback to its input side  $\rightarrow S_{12} = 0$ .

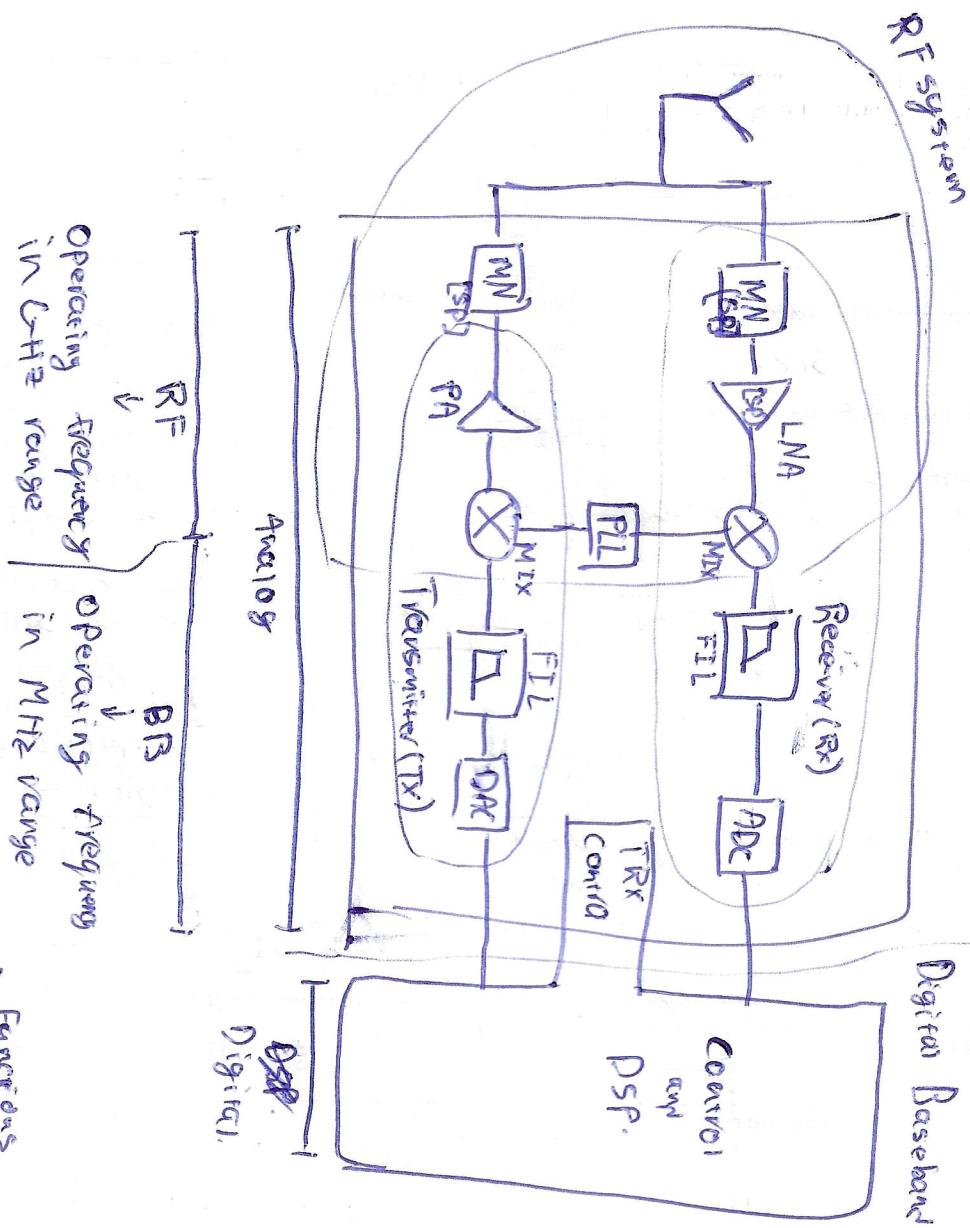
|  |  |
|--|--|
| Condition for "unconditionally stable" device, general case  | for all $ \Gamma_L  < 1$ and $ \Gamma_S  < 1$<br>$\Rightarrow \begin{cases}  \Gamma_{in}  = \left  S_{11} + \frac{S_{12}S_{21}\Gamma_L}{1-S_{22}\Gamma_L} \right  < 1 \\  \Gamma_{out}  = \left  S_{22} + \frac{S_{12}S_{21}\Gamma_S}{1-S_{11}\Gamma_S} \right  < 1 \end{cases}$   |
| Conditions for "unconditionally stable" device, unilateral case<br>$S_{12} = 0$  | $ \Gamma_{in}  =  S_{11}  < 1$ <del>stable</del><br>$ \Gamma_{out}  =  S_{22}  < 1$<br>$S_{12} = 0$ .  |
| Center and radius of the stability circles, load side<br><i>draw these circles to find unstable regions of amplifier</i> | $C_L = \frac{(S_{22} - \Delta S_{11}^*)^*}{ S_{22} ^2 -  \Delta ^2}$ (center)<br>$R_L = \frac{ S_{12}S_{21} }{ S_{22} ^2 -  \Delta ^2}$ (radius)<br>$\Delta = S_{11}S_{22} - S_{12}S_{21}$   |
| Center and radius of the stability circles, source side  | $C_S = \frac{(S_{11} - \Delta S_{22}^*)^*}{ S_{11} ^2 -  \Delta ^2}$ (center)<br>$R_S = \frac{ S_{12}S_{21} }{ S_{11} ^2 -  \Delta ^2}$ (radius)<br>$\Delta = S_{11}S_{22} - S_{12}S_{21}$   |
| Test for unconditional stability, general case   | $ \Delta  =  S_{11}S_{22} - S_{12}S_{21}  < 1$<br>and<br>$K = \frac{1 -  S_{11} ^2 -  S_{22} ^2 + \Delta^2}{2 S_{12}S_{21} } > 1$  |
| Test for unconditional stability, unilateral case  | $ S_{11}  < 1$<br>$ S_{22}  < 1$<br>$S_{12} = 0$   |
| Noise figure of a 2-port amplifier   | $F = F_{min} + \frac{r_N}{g_S} \left  \underline{y}_S - \underline{y}_{opt} \right ^2$ admittance form<br>$F = F_{min} + 4r_N \frac{\left  \underline{\Gamma}_S - \underline{\Gamma}_{opt} \right ^2}{(1 -  \underline{\Gamma}_S ^2) \cdot (1 +  \underline{\Gamma}_{opt} ^2)}$ reflection coeff form  |
| Constant noise circles<br><i>HELP: select <math>\Gamma_S</math> for desired F in LNA input matching</i>                  | $\underline{C}_F = \frac{\underline{\Gamma}_{opt}}{1+N}$ center<br>$R_F = \frac{1}{1+N} \sqrt{N^2 + N(1 -  \underline{\Gamma}_{opt} ^2)}$ radius } z.<br>$F_{min} = 10^{\frac{NF_{min}}{10}}$<br>$\Delta F_n = N = (F - F_{min}) \frac{\left  1 + \underline{\Gamma}_{opt} \right ^2}{4r_N} = \frac{\left  \underline{\Gamma}_S - \underline{\Gamma}_{opt} \right ^2}{1 -  \underline{\Gamma}_S ^2}$ 1 |

\* if  $T_S n_f < 1$  and  $|(\underline{C}_F - \underline{R}_L)| > 1 \rightarrow 2\text{-port unconditionally stable} //$



Analog Transceiver (TRX) - Radio

- Data conversion
- Filtering / selectivity
- Frequency conversion
- Amplification
- Frequency synthesis



Operating frequency  
in GHz range

Operating frequency  
in MHz range

| Functions               | Building blocks | Symbols           |
|-------------------------|-----------------|-------------------|
| 1. digitization         | ADC             | IN → ADC → OUT    |
| 2. amplification        | Amplifier       | IN → OUT          |
| 3. filtering            | Filter          | IN → FILTER → OUT |
| 4. frequency conversion | Mixer           | IN → MIXER → OUT  |

• SFDR, LDR  $\rightarrow$  usable range of system without significant distortion.

• linear dynamic range:  $LDR = P_{dB} - P_{noise}$

• Spurious-Free Dynamic Range:  $SFDR = \frac{2}{3}(IIP_3 - P_{noise})$

|   |  |                              |
|---|--|------------------------------|
| Output noise, input noise, equivalent noise temperature, noise factor and noise figure<br><br>noise and LNA design  | $N_o = Gk_B(T_0 + T_e)B$<br>$N_i = k_B T_0 B$<br>$F = \frac{\overline{N}_i}{\overline{S}_o} = \frac{S_i N_o}{S_o N_i} = \frac{1}{G} \frac{Gk_B(T_0 + T_e)B}{k_B T_0 B} = 1 + \frac{T_e}{T_0}$<br>$NF = 10 \log_{10} F$   | $\frac{SNR_{in}}{SNR_{out}}$ |
| Three-stage amplifier:<br>Output noise ( $P_{n,total}$ ), noise factor ( $F_{total}$ ) noise figure ( $NF_{total}$ )<br><br>$T_{e,1} = \frac{T_{e,1}}{G_1} + \frac{T_{e,2}}{G_1 G_2} + \frac{T_{e,3}}{G_1 G_2 G_3} + \dots \rightarrow$ | $P_{n,total} = G_{A3} G_{A2} G_{A1} P_{n,in} + G_{A3} G_{A2} P_{n1} + G_{A3} P_{n2} + P_{n3}$<br>$F_{total} = \frac{P_{n,total}}{G_{A3} G_{A2} G_{A1} P_{n,in}}$<br>$F_{total} = 1 + \frac{P_{n1}}{G_{A1} P_{n,in}} + \frac{P_{n2}}{G_{A1} G_{A2} P_{n,in}} + \frac{P_{n3}}{G_{A1} G_{A2} G_{A3} P_{n,in}}$<br>$F_{total} = F_1 + \frac{F_2 - 1}{G_{A1}} + \frac{F_3 - 1}{G_{A1} G_{A2}} \rightarrow \text{idem w.r.t. } 10 \log_{10} (\text{dB})$<br>$NF_{total} = 10 \log_{10} F_{total}$<br>Noise factor of single stage $F_j = 1 + \frac{P_{nj}}{G_{Aj} P_{n,in}}, j = 1, 2, 3$<br>Noise figure of single stage $NF_j = 10 \log_{10} F_j, j = 1, 2, 3$ | $(10 \log_{10} \dots)$       |
| Receiver sensitivity<br><br>$\uparrow \text{LNA influenced by receiver sensitivity.}$<br><br>$P_{sens} \approx -174 \text{ dBm/Hz for } T_0 = 290 \text{ K}$  | $P_{sens} [\text{dBm}] = k_B T_0 B [\text{dBm}] + NF_{total} [\text{dB}] + SNR [\text{dB}]$<br>$P_{sens} [\text{dBm}] = -174 + NF_{total} + 10 \log_{10} B + SNR$<br>$k_B = \text{Boltzmann constant}, k_B = 1.38 \cdot 10^{-23} \frac{\text{Watt} \cdot \text{s}}{\text{K}}$  |                              |
| Conversion Watt to dBm  | $P_{sens} [\text{dBm}] = 10 \log_{10} \frac{P_{sens} [\text{Watt}]}{1 \text{mWatt}}$<br>$P_{sens} [\text{dBm}] = 10 \log_{10} \frac{P_{sens} [\text{Watt}]}{10^{-3} \text{Watt}}$  |                              |
| Gain conversion from linear to dB   | $G [\text{dB}] = 10 \log_{10} G$   |                              |
| Friis radio link formula<br><br>• Shannon Capacity:<br>$C = B \cdot \log_2(1 + SNR)$ .<br><br>• received power:<br>$P_{RX} = P_{TX} \cdot G_{TX} \cdot G_{RX} - L_{path}$<br>- Leaky  | $P_{RX} = P_{TX} G_{TX} G_{RX} \left( \frac{\lambda}{4\pi R} \right)^2$<br>$P_{RX}$ - power at RX input<br>$P_{TX}$ - power at TX output<br>$G_{RX}$ - RX antenna gain<br>$G_{TX}$ - TX antenna gain<br>$\lambda$ - wave length<br>$\lambda = \frac{c}{f}$<br>$c$ - speed of light, $c = 3 \cdot 10^8 \frac{\text{m}}{\text{s}}$<br>$f$ - frequency  |                              |

### • Bit Error Rate (BER)

↳ depends on:

↳ SNR

↳ modulation scheme.

• energy per bit:  $E_b = \frac{S}{R_b}$

• noise power:  $N = N_0 \cdot B$

• ratio:  $E_b/N_0 = \frac{S}{N} = \frac{B}{R_b}$

3

$$FSPL = \left( \frac{P_{Tx}}{P_{Rx}} \right)^2$$

# Amplifier Gain Equations + not are missing.

## Module 4

given:  $P_L = \frac{|V_2|^2}{2Z_0} (1 - |\Gamma_L|^2)$

$$P_{in} = \frac{|V_1|^2}{2Z_0} (1 - |\Gamma_{in}|^2)$$

Note:

$P_{AVS}$   $\rightarrow$  Power available from source:  $Z_s^* = Z_{in}$

$P_{in}$   $\rightarrow$  When source impedance is conjugately matched to input impedance

$$P_{AVS} = \frac{|V_s|^2}{2Z_0} (1 - |\Gamma_s|^2)$$

$P_{AVN}$   $\rightarrow$  Power available from network:  $Z_i^* = Z_{out}$

$P_L$   $\rightarrow$  when load impedance is conjugately matched to output impedance

$$P_{AVN} = \frac{|V_2|^2}{2Z_0} (1 - |\Gamma_{out}|^2)$$

Power Gain:  $G = \frac{P_L}{P_{in}} = \frac{|S_21|^2 (1 - |\Gamma_L|^2)}{(1 - |\Gamma_{in}|^2) |1 - S_{22}\Gamma_L|^2}$

Available Power Gain:  $G_A = \frac{P_{AVN}}{P_{AVS}} = \frac{|S_21|^2 (1 - |\Gamma_s|^2)}{|1 - S_{21}\Gamma_s|^2 (1 - |\Gamma_{out}|^2)}$

Tranformer Power Gain:  $G_T = \frac{P_L}{P_{AVS}} = \frac{P_L}{P_{AVN}} = \frac{|S_21|^2 (1 - |\Gamma_s|^2) (1 - |\Gamma_L|^2)}{|1 - \Gamma_s \Gamma_{in}|^2 |1 - S_{22}\Gamma_L|^2}$

Unilateral PT Producer Power gain  $\rightarrow G_{TU} \rightarrow$  given.

